L Number	Hits	Search Text	DB	Time stamp
-	29676	magnetic near2 memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 23:21
-	13267	conductive adj line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 22:57
-	121130	(conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 22:59
-	2237	(magnetic near2 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 22:59
-	41703	magnetic near3 memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 23:43
-	2840	(magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 23:44
-	183281	(current adj2 supply) or (voltage adj2 supply)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 23:55
-	368	((magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))) and ((current adj2 supply) or (voltage adj2 supply))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/27 23:46
-	164738	current with direction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 00:31
-	46893	multipl$4 near2 line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 00:32
-	34	((magnetic near3 memory) and (((magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))) and ((current adj2 supply) or (voltage adj2 supply)))) and (multipl$4 near2 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 00:32
-	368	(magnetic near3 memory) and (((magnetic near3 memory) and ((conductive adj2 line) or (electrical adj2 line) or ((bit or word) adj line))) and ((current adj2 supply) or (voltage adj2 supply)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:06
-	688	magnetic adj memory adj cell$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:07

-	534	(magnetic adj memory adj cell$1) and line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:07
-	109	((magnetic adj memory adj cell$1) and line) and current adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:08
-	2167	mram and line	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:08
-	1163	(mram and line) and source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:08
-	633	((mram and line) and source) and supply	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:09
-	753	((mram and line) and source) and suppl$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:09
-	508	(((mram and line) and source) and suppl$4) and 365/$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:10
-	252	((((mram and line) and source) and suppl$4) and 365/$.ccls.) and (chang$3 with direct$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:27
-	168	((((mram and line) and source) and suppl$4) and 365/$.ccls.) and (chang$3 with direct$4 with current)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/28 01:27